

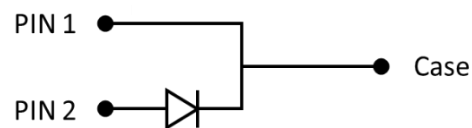
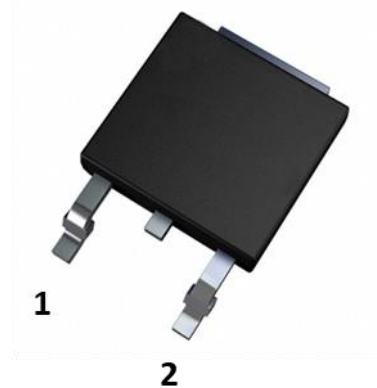
# NW12005IX1

## 1200 V 5 A SiC Schottky diodes

Parameter	Value	Unit
$I_F; T_c = 155\text{ °C}$	5	A
$V_F; I_F = 5\text{ A}$	1.35	V
$Q_C; V_R = 800\text{ V}$	28	nC

### Features

- Zero reverse recovery
- High-speed switching
- Temperature independent switching behavior
- $V_{RPM} = 1200\text{ V}$
- $I_F = 5\text{ A}$  (155 °C)
- $V_F = 1.35\text{ V}$  (25 °C)
- $Q_C = 28\text{ nC}$
- Junction temperature -55 °C to 175 °C
- Package type: TO-252-2L
- RoHS compliant



### Applications

- Industrial power supplies
- Battery chargers
- Solar inverters
- Switch mode power supplies

### Description

The NW12005IX1 Schottky barrier diode (SBD) is based on NovaWave's advanced SiC power technology resulting in high performance and long-term reliability. It supports high-temperature operation while showing minimal losses, zero reverse recovery, and low leakage current up to 1200V.

**Table 1 Maximum Ratings**
 $T_j = 25\text{ °C}$ , unless otherwise specified.

Parameter	Symbol	Value	Unit	Test conditions
Repetitive peak reverse voltage	$V_{RRM}$	1200	V	$T_C = 25\text{ °C}$
Surge peak reverse voltage	$V_{RSM}$	1200		
DC reverse voltage	$V_{DC}$	1200		
Continuous forward current	$I_F$	22	A	$T_C = 25\text{ °C}$
		10		$T_C = 135\text{ °C}$
		5		$T_C = 155\text{ °C}$
Surge non-repetitive forward current	$I_{FSM}$	55	A	$T_C = 25\text{ °C}$ , $t_p = 10\text{ ms}$ , half sine wave $D = 0.1$
Surge repetitive forward current	$I_{FRM}$	40	A	$T_C = 25\text{ °C}$ , $t_p = 10\text{ ms}$ , half sine wave $D = 0.1$
Power dissipation	$P_{tot}$	134	W	$T_C = 25\text{ °C}$
$i^2t$ value	$\int i^2 dt$	15	$A^2s$	$T_C = 25\text{ °C}$ , $t_p = 10\text{ ms}$ ,
Operating Junction Temperature	$T_J$	-55 to +175	$^{\circ}C$	-
Storage Temperature	$T_S$	-55 to +150	$^{\circ}C$	-

**Table 2 Thermal Characteristics**

Parameter	Symbol	Value	Unit
Thermal Resistance Junction-to-Case – (bottom side)	$R_{TH,J-C}$	1.12	$^{\circ}C/W$

**Table 3 Static Electrical Characteristics**

Parameters	Symbol	Min	Typ	Max	Unit	Condition
DC blocking voltage	$V_{DC}$	1200	-	-	V	$I_R = 100 \mu A$
Forward voltage	$V_F$	-	1.35	1.50	V	$I_F = 5 A, T_j = 25 \text{ }^\circ C$
		-	1.85	2.20		$I_F = 5 A, T_j = 175 \text{ }^\circ C$
Reverse current	$I_R$	-	1	20	$\mu A$	$V_R = 1200 V, T_j = 25 \text{ }^\circ C$
		-	3	80		$V_R = 1200 V, T_j = 175 \text{ }^\circ C$

**Table 4 Dynamic Electrical Characteristics**

Total capacitance	C	-	400	-	$\mu F$	$V_R = 0 V, f = 1 \text{ MHz}$
		-	27	-		$V_R = 400 V, f = 1 \text{ MHz}$
		-	20	-		$V_R = 800 V, f = 1 \text{ MHz}$
Total capacitive charge	$Q_C$	-	28	-	nC	$V_R = 800 V$
Capacitive stored energy	$E_C$	-	8.2	-	$\mu J$	$V_R = 800 V$

### Electrical Performance Graphs

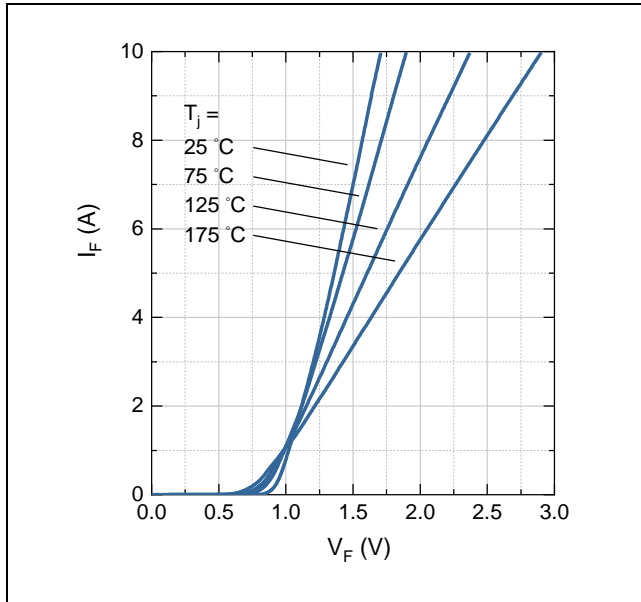


Figure 1: Typical Forward characteristics

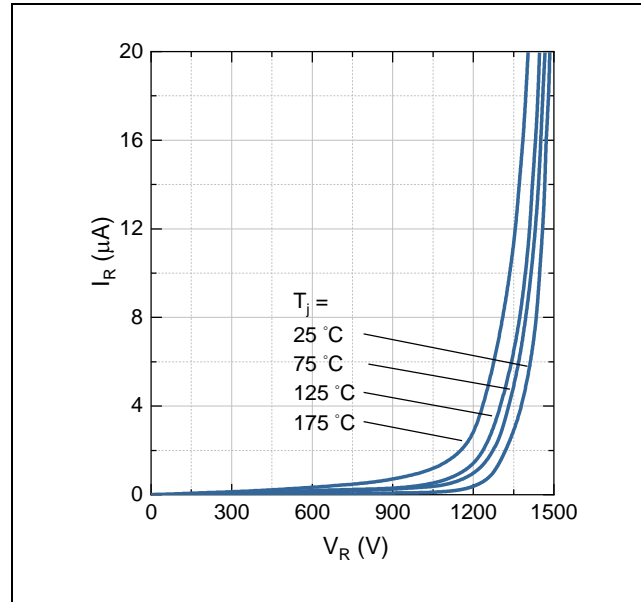


Figure 2: Typical Reverse characteristics

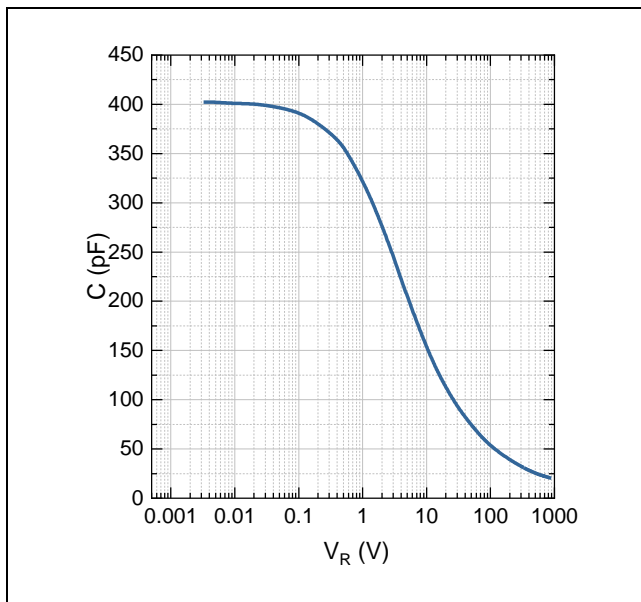


Figure 3: Typical Junction Capacitance vs. Reverse Voltage

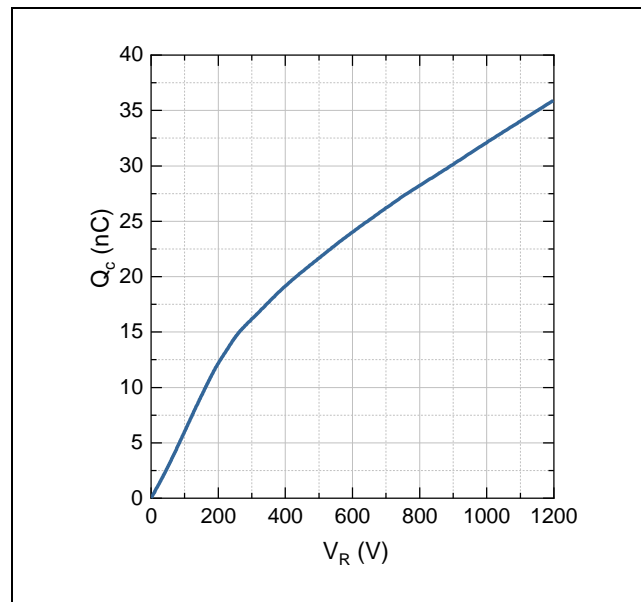


Figure 4: Typical Capacitive Charge vs. Reverse Voltage

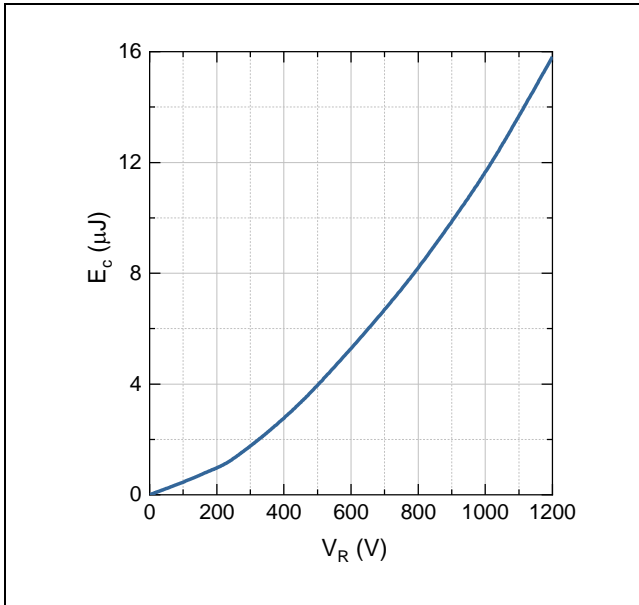


Figure 5: Typical Capacitive Energy vs. Reverse Voltage

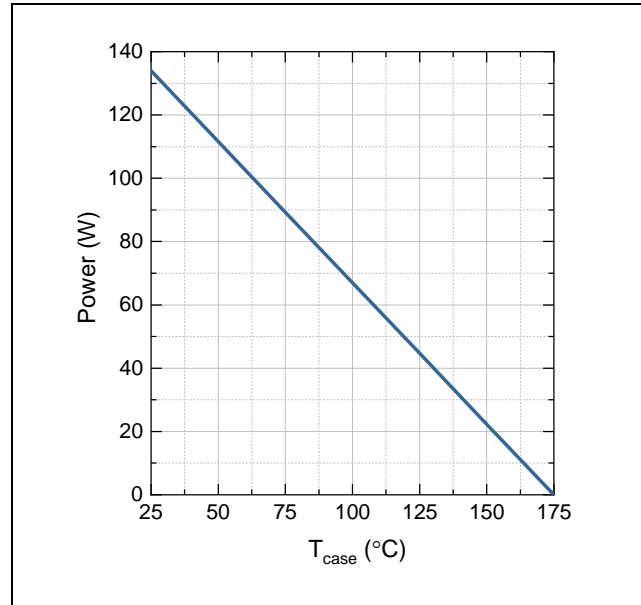


Figure 6: Power Derating vs.  $T_{\text{case}}$

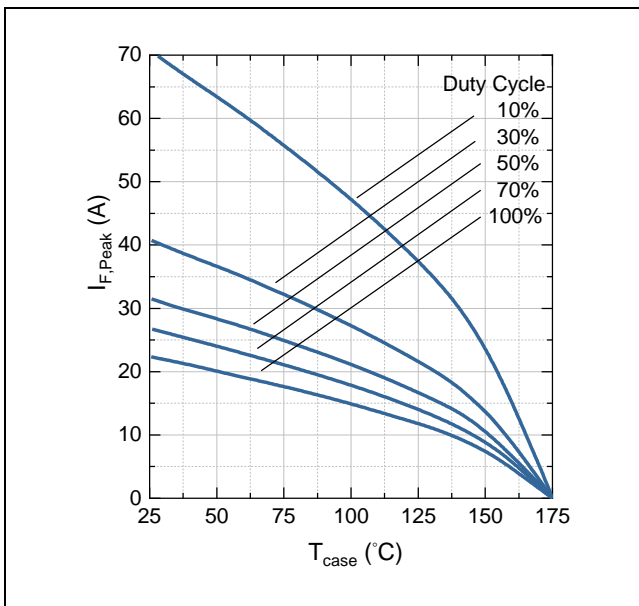
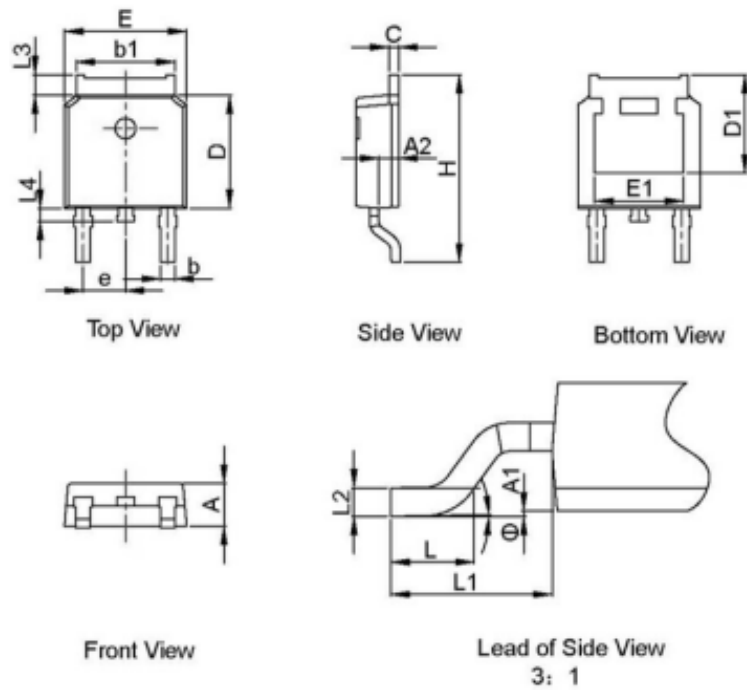


Figure 7: Current Derating vs.  $T_{\text{case}}$

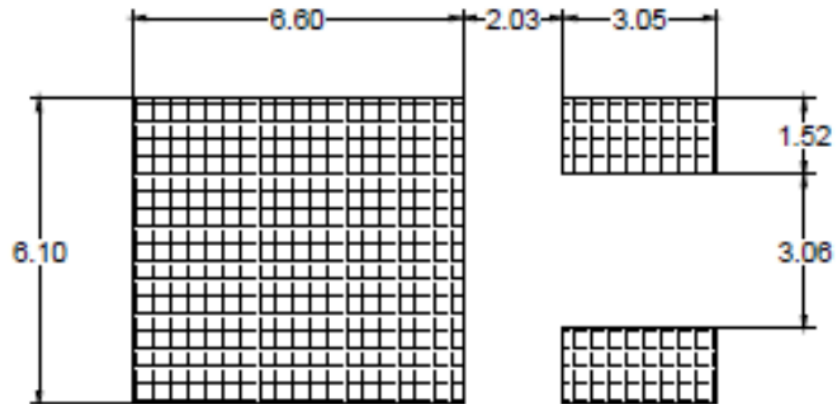
## Package Information



Dimension unit: [mm]			
Symbol	Min	Nom	Max
A	2.20	2.30	2.38
A1	0	-	0.127
A2	0.97	1.07	1.17
b	0.68	0.78	0.90
b1	5.20	5.33	5.46
c	0.43	0.53	0.61
D	5.98	6.10	6.22
D1	5.30 REF		
E	6.40	6.60	6.73
E1	4.63	-	-
e	2.286 BSC		
H	9.40	10.10	10.50
L	1.38	1.50	1.75
L1	2.743 REF		
L2	0.51 BSC		
L3	0.88	-	1.28
L4	0.50	-	1.00
theta	0°	-	8°

## Recommended Solder Pad Layout

Note: all dimensions are in mm



TO-252-2L

## Ordering information

Parameters	Symbol
Part number	NW12005IX1
Package	TO-252-2L
Unit quantity	2500 ea
Package type	Tape & Reel

## Disclaimer

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